

250 mW Linear Power Amplifier and T/R Switch 1.8 - 2.0 GHz AM55-0004

Features

- Operates Over Full PCN/PCS/PHS Bands
- Operates Over +3 V to +5 V Supply Voltage
- +24 dBm P_{1dB} Typical at PA Out
- 35% PAE @ P_{1dB} for Linear Operation
- On-Chip T/R Switch, Linear Operation to +30 dBm
- Low Cost SSOP-28 Plastic Package

Description

M/A-COM's AM55-0004 power amplifier/switch integrates a power amplifier and transmit/receive switch in a low cost SSOP package. The power amplifier delivers +24 dBm of linear power with high efficiency and can be operated at supply voltages as low as 2.7 V. It is ideally suited for QPSK or other linearly modulated systems in the 1.8 to 2.0 GHz frequency band.

The power amplifier/switch is fully monolithic and requires only one output capacitor for power match. The T/R switch achieves good insertion loss and isolation without degrading the overall linearity.

The AM55-0004 is ideally suited for final stage power amplification in linear TDD systems. The integrated switch is convenient for duplexing. The AM55-0004 can also be used as a driver stage for high power systems. Typical applications include Japanese PHS systems or PCN/PCS transmit chains.

M/A-COM's AM55-0004 is fabricated using a mature 0.5-micron gate length GaAs process. The process features full passivation for increased performance and reliability.

Typical Electrical Specifications

SSOP-28



Dimensions are inches over millimeters.

Ordering Information

| Part Number | Description |
|--------------|----------------------------------|
| AM55-0004 | SSOP 28-Lead Plastic Package |
| AM55-0004TR | Forward Tape & Reel* |
| AM55-0004RTR | Reverse Tape & Reel [*] |
| AM55-0004SMB | Designer's Kit |

* If specific reel size is required, consult factory for part number assignment.

Test conditions: Frequency: 1.9 GHz, V_{DD1} = V_{DD2} = 4.8 V ±10%, V_{G1} adjusted for 30 mA quiescent bias on V_{DD1}, V_{G2} adjusted for 65 mA quiescent bias on V_{DD2} , T_A = +25°C

| Parameter | Units | Min. | Тур. | Max. |
|---|-------|------|-------|------|
| Power Amplifier | 1 | | | |
| Linear Gain | dB | 22 | 24 | |
| Power Output @ P _{1dB} at PA OUT port | dBm | 22.5 | 24 | |
| Current From Positive Supply @ P _{1dB} | mA | 75 | 175 | 275 |
| Input VSWR | | | 2.0:1 | |
| T/R Switch | | 1 | | |
| Insertion Loss | dB | | 0.6 | 1.0 |
| Input Match | | | 1.5:1 | |
| Isolation | dB | 15 | 20 | |

Specifications Subject to Change Without Notice

V2.00

Absolute Maximum Ratings¹

| Parameter | Absolute Maximum |
|---------------------------------|-------------------------|
| Max. Input Power ² | +23 dBm |
| Operating Voltages ² | $V_{DD} = 7 V$ |
| | V _{GG} = -5 V |
| | $V_{DD} - V_{GG} = 8 V$ |
| Operating Temperature | -40°C to +85°C |
| Storage Temperature | -65°C to +150°C |

1. Exceeding these limits may cause permanent damage.

2. Ambient temperature $(T_A) = +25^{\circ}C$

Pin Configuration

| Pin No. | Pin Name | Description | |
|---------|------------------|---|--|
| 1 | GND | DC and RF Ground | |
| 2 | VSW | Complimentary T/R Switch Control, -4 V Tx mode/0 V Rx mode | |
| 3 | GND | DC and RF Ground | |
| 4 | Tx IN | Transmit side of T/R switch | |
| 5 | GND | DC and RF Ground | |
| 6 | GND | DC and RF Ground | |
| 7 | ANT IN/OUT | Common port of T/R switch which is connected to the antenna | |
| 8 | GND | DC and RF Ground | |
| 9 | Rx OUT | Receive side of T/R switch | |
| 10 | GND | DC and RF Ground | |
| 11 | GND | DC and RF Ground | |
| 12 | V _{DD1} | Positive bias for the first stage of PA, +2.7 to +6.0 volts | |
| 13 | SAVE Tx | Sleep mode control of first stage of PA ONLY 0 V — first PA stage on -4 V — first PA stage off | |
| 14 | GND | DC and RF Ground | |
| 15 | GND | DC and RF Ground | |
| 16 | PA IN | RF input of the Power Amplifier | |
| 17 | GND | DC and RF Ground | |
| 18 | V _{G1} | Negative bias control for the first PA stage, voltage divider is on the MMIC, adjusted to set V_{DD1} quiescent bias current, which is typically 30 mA. Input impedance: 10 k Ω | |
| 19 | GND | DC and RF Ground | |
| 20 | V _{G2} | Negative bias control for the second PA stage, adjusted to set V_{DD2} quiescent bias current, which is typically 65 mA. Input impedance: > 1M Ω | |
| 21 | GND | Second Stage DC and RF Ground | |
| 22 | GND | Second Stage DC and RF Ground | |
| 23 | GND | Second Stage DC and RF Ground | |
| 24 | GND | Second Stage DC and RF Ground | |
| 25 | PA OUT | RF output of the Power Amplifier | |
| 26 | V _{DD2} | Positive bias for the second stage of the PA, +2.7 to +6.0 volts | |
| 27 | VSW | T/R Switch Control, 0 V Tx mode/-4 V Rx mode | |
| 28 | GND | DC and RF Ground | |

Truth Table

| Operating Mode | vsw | vsw | SAVE Tx |
|----------------|------------|------------|------------|
| PA Tx | Х | Х | 0 V |
| PA Sleep | Х | Х | -4.0 Volts |
| T/R Switch Tx | 0 Volts | -4.0 Volts | Х |
| T/R Switch Rx | -4.0 Volts | 0 Volts | Х |

X - Don't Care

Functional Diagram and Pin Configuration



Specifications Subject to Change Without Notice

Power Amplifier Small Signal Performance¹

Power Amplifier CW Performance at 1.9 GHz¹



1. All data measured at T_A = +25°C and V_{G1}, V_{G2} adjusted for first stage quiescent current of 30 mA and second stage current of 65 mA, respectively.

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Power Amplifier Temperature Performance¹









Power Amplifier Spurious Response at Various Supply Voltages¹



13 16 19 FUNDAMENTAL P_{OUT} (dBm)

1. All data measured at $T_A = +25^{\circ}C$ and V_{G1} , V_{G2} adjusted for first stage quiescent current of 30 mA and second stage current of 65 mA, respectively.

50

*́*10

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Power Amplifier Spectral Response Under Modulation Drive

(π /4 DQPSK, α = 0.5, 384 kB/sec, 9-bit PN code)



Output Power Under Modulation²

| V _D (volts) | P _{OUT} (dBm) |
|------------------------|------------------------|
| 3 | 20.5 |
| 3.6 | 21.4 |
| 4 | 22.2 |
| 4.8 | 23.4 |
| 6 | 23.7 |

1. Spectral output is tested under the following conditions: Modulation scheme is $\pi/4$ DQPSK with a bit transfer rate of 384 kB/sec and a root Nyquist filter with $\alpha = 0.5$ per RCR STD-28. The spectrum analyzer settings are as follows:

Resolution bandwidth: 10 kHz Video bandwidth: 100 kHz Sweep time: 5 seconds

2. This chart documents the modulated output power delivered for a fixed adjacent channel interference (ACI) rejection of 55 dBc at a 600-kHz offset.





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Recommended PCB Configuration



External Circuitry Parts List

| Label | Value | Purpose |
|---------|----------------|------------------------------------|
| C1 - C5 | 1000 pF | Low frequency bypass |
| C6 - C8 | 68 pF | RF bypass |
| C9 | 1.5 pF | Output power tuning |
| C10 | 15 pF | Reduces low frequency gain |
| R1 | 2.7 k Ω | Voltage divider to V _{G2} |
| R2 | 1.5 k Ω | Voltage divider to V _{G2} |
| R3 | 150 Ω | Reduces low frequency gain |
| Tline | 0.250 in. long | Power match |

All off-chip components are low-cost surface mount components obtainable from multiple sources. (0.020 in. x 0.040 in. or 0.030 in. x 0.050 in.)



Cross-Section View

The PCB dielectric between RF traces and RF ground layers should be chosen to reduce RF discontinuities between 50- Ω lines and package pins. M/A-COM recommends an FR-4 dielectric thickness of 0.008 in. (0.2 mm), yielding a 50- Ω line width of 0.015 in. (0.38 mm). The recommended metalization thickness is 1 oz. copper.

Shaded traces are vias to DC routing layer and traces on DC routing layer.

Biasing Procedure

The AM55-0004 requires that V_{GG} bias be applied prior to **any** V_{DD} bias. Permanent damage may occur if this procedure is not followed. All FETs in the PA will draw excessive current and damage internal circuitry.



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External Circuitry

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Designer's Kit (AM55-0004SMB)

The AM55-0004SMB Designer's Kit allows for immediate evaluation of M/A-COM's AM55-0004 integrated Power Amplifier and T/R Switch. The evaluation board consists of an AM55-0004, recommended external surface mount circuitry, RF connectors and a DC multipin connector, all mounted to a multi-layer FR-4 PCB. Other items included in the Designer's Kit: a floppy disk (with typical performance data and a .DXF file of the recommended PCB layout) and any additional Application Notes. The AM55-0004SMB PA/Switch evaluation PCB and block diagram are illustrated below with all functional ports labeled.

P/A Switch Sample Board



Functional Block Diagram



DC Connector Pinout

| PCB DC Connector | Function | Device Pin Number |
|---------------------|----------------------------|----------------------|
| 1 | N/C | N/C |
| 2 | V _{DD1} (+ 4.8 V) | 12 |
| 3 | SAVE Tx (0 V/-4 V) | 13 |
| 4 | GND | N/C |
| 5 | SAVE Tx (0 V/-4 V) | 13 |
| 6 | V _{G1} | 18 |
| 7 | VSW | 2 |
| 8 | GND | N/C |
| 9 | VSW | 2 |
| 10 | V _{G1} | 18 |

| PCB DC Connector | Function | Device Pin Number |
|---------------------|-----------------------------|----------------------|
| 11 | VSW | 27 |
| 12 | V _{G1} | 18 |
| 13 | VSW | 27 |
| 14 | GND | N/C |
| 15 | V _{G2} | 20 |
| 16 | V _{G1} | 18 |
| 17 | N/C | N/C |
| 18 | V _{G2} | 20 |
| 19 | N/C | N/C |
| 20 | V _{DD2} (+ 4.8 V) | 26 |

Specifications Subject to Change Without Notice

V 2.00

AM55-0004SMB Biasing Procedure

In order to prevent transients which may damage the MMIC, please adhere to the following procedure.

- Turn on all power supplies and set all voltages to 0 volts BEFORE connecting the power supplies to the DC connector.
- Apply -4.0 volt supply or GND to DC connector pin 9 ($\overline{\text{VSW}}$, see truth table for desired mode).
- Apply -4.0 volt supply or GND to DC connector pin 13 (VSW, see truth table for desired mode).
- Apply a -4.0 volt supply to the DC connector pin 16 (V_{G1}).
- Apply a -4.0 volt supply to the DC connector pin 18 (V_{G2}).
- Apply a +4.8 volt supply to the DC connector pin 2 (V_{DD1}).
- Apply a +4.8 volt supply to the DC connector pin 20 (V_{DD2}).
- Apply GND to DC connector pin 5 (Save Tx).
- Adjust V_{G1} supply for desired V_{DD1} quiescent current (typically 30 mA).
- Adjust V_{G2} supply for desired V_{DD2} quiescent current (typically 65 mA).
- Change voltage on DC connector pin 5 as required (Save Tx, see truth table for desired mode).
- Apply RF power and test.
- To power off, reverse above procedure
 - 1. Set $V_{G1} \& V_{G2}$ to -4 V.
 - 2. Set V_{DD1} & V_{DD2} to 0 V.
 - 3. Set control voltage supplies to 0 V.
 - 4. Disconnect bias lines from DC connector.
 - 5. Turn off power supplies.

Evaluation PCB and RF Connector Losses

| Port Reference | Estimated Loss (dB) |
|----------------|---------------------|
| PA IN | 0.15 |
| PA OUT | 0.20 |
| Tx IN | 0.20 |
| ANT IN/OUT | 0.20 |
| Rx OUT | 0.20 |

The DC connector on the Designer's Kit PCB allows selection of all the device's operating modes. It is accomplished by one or more of the following methods:

- 1. A mating female multi-pin connector (Newark Electronics Stock # 46F-4658, not included)
- 2. Wires soldered to the necessary pins (not included)
- 3. Clip leads (not included)
- 4. A combination of clip leads or wires and jumpers (jumpers included as required)

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